L Number	Hits	Search Text	DB	Time stamp
2	13	(("257/314-322,390,391").CCLS.) and wells and @pd > 20010917 not dram	USPAT	2002/06/04 09:56
3	3	((("257/314-322,390,391").CCLS.) and wells not dram) and @ad < 19980820 and @pd > 20010917	USPAT	2002/06/04 09:57
4	48	(("257/314-322,390,391").CCLS.) and (ONO with oxide) and @pd > 20010917	USPAT	2002/06/04 10:01
5	175	((("257/314-322,390,391").CCLS.) not dram) and (((insulation nitride dielectric oxide) adj layers) with floating)	USPAT	2002/06/04 10:04
6	14	((("257/314-322,390,391").CCLS.) not dram) and peripheral and logic and @pd > 20010917	USPAT	2002/06/04 10:05
8	115	((("257/314-322,390,391").CCLS.) not dram) and insulat$3 and @pd > 20010917	USPAT	2002/06/04 10:05
9	38	((("257/314-322,390,391").CCLS.) not dram) and (insulation dielectric oxide) adj layers and @pd > 20010917	USPAT	2002/06/04 10:07
13	33	(("5748536"	"6144064"	"6103573"	"5907172"	"6157060"	"5969383"	"5939749"	"504BF88T"; JBQ428ZB02/063208080732 "5309371" | ' (("09321156" "11074389" "07142617" "07147336" "09321157" "2000188344").pn.)		
.	150	((("257/314-322,390,391").CCLS.) and wells not dram) and @pd < 19980820	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/04 09:57
.	1	03219496.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/03 18:55
.	251	(("257/314-322,390,391").CCLS.) and peripheral and logic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/02 17:28
.	63	(("257/314-322,390,391").CCLS.) and peripheral with logic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/17 18:
.	3364	(("257/314-322,390,391").CCLS.) not dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/17 18:04
.	211	((("257/314-322,390,391").CCLS.) not dram) and peripheral and logic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/04 10:04
.	44	((("257/314-322,390,391").CCLS.) not dram) and peripheral with logic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/04 10:03
.	15	(((("257/314-322,390,391").CCLS.) not dram) and peripheral with logic) and eprom	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/17 18:11
.	704	((("257/314-322,390,391").CCLS.) not dram) and insulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/04 10:05
.	2449	((("257/314-322,390,391").CCLS.) not dram) and (insulation dielectric oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/17 18:18

.	524	((("257/314-322,390,391").CCLS.) not dram) and (insulation dielectric oxide) adj layers	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/04 10:05
.	169	((("257/314-322,390,391").CCLS.) not dram) and (((insulation nitride dielectric oxide) adj layers) with floating)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/04 10:03
.	43	((("257/314-322,390,391").CCLS.) not dram) and peripheral with logic and regions	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/17 19:48
.	39	((("257/314-322,390,391").CCLS.) not dram) and peripheral with logic and regions	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/09/17 19:48
.	25	(("257/314-322,390,391").CCLS.) and (ONO with oxide) and @pd < 19940101	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/04 10:00
.	6	((("257/314-322,390,391).CCLS.) and @pd > 20010914 and @ad < 19990820) and peripheral and logic	USPAT	2002/06/02 17:29
.	2483	(257/314-322,390,391).CCLS.	USPAT	2002/06/02 17:?7
.	272	(("257/314-322,390,391").CCLS.) and wells	USPAT	2002/06/04 08: